

INTERCONNECT FOR TRANSMITTING SIGNALS BETWEEN A DEVICE AND A TESTER

TECHNICAL FIELD

5 This specification relates generally to an interconnect for transmitting signals between a device and a tester.

BACKGROUND

10 Wafer-level testing includes testing dice on a wafer. In this specification, "dice" is used as the plural of "die". Since dice are fragile, it is preferable not to touch any die more than once during test. However, since dice are typically patterned on a circular wafer, testing any set of dice may involve touching several dice more than once. Furthermore, a device that touches the dice may have to partially step (walk) off of the wafer for all dice to be touched. The ratio of actual
15 touchdowns to theoretically necessary touchdowns is called touchdown efficiency.

 There is a certain amount of test circuitry that needs to have a good electrical path (e.g., low loss, low inductance, and low crosstalk) to test a die. This circuitry often takes-up several square inches of a test board per die being tested. Typically, a good electrical path is obtained by implementing a very short electrical path on the
20 test board that is used to perform wafer-level testing.

 To address the touchdown efficiency problem, it is helpful to test dice in a tight group. To address the test circuitry problem, it is helpful to test dice that are spread out on the wafer, so that one die's test circuitry does not electrically or mechanically

interfere with test circuitry of an adjacent die. These two competing requirements affect the ability to perform parallel testing at the wafer level.

SUMMARY

5 An example system comprises: a circuit board comprising electrical elements arranged at a first pitch; a wafer comprising contacts arranged at a second pitch, where the second pitch is less than the first pitch; and an interconnect comprising additively-manufactured electrical conduits that are part of an electrical pathway between the electrical elements and the contacts, where the additively-manufactured
10 electrical conduits comprise electrically-conductive material. The example system may include one or more of the following features, either alone or in combination. The additively-manufactured electrical conduits may comprise the electrically conductive material surrounded by at least one dielectric material. The at least one dielectric material may be substantially surrounded by a layer of electrically-conductive material. The at least one dielectric material may include multiple dielectric materials. The additively-manufactured electrical conduits may have a coaxial structure and the at least one dielectric may include air plastic and/or ceramic. The system may include an interposer between the interconnect and the circuit board. The interposer may be a part of the electrical pathway between the
20 electrical elements and the contacts. The system may include electrically-conductive pins between additively-manufactured electrical conduits in the interconnect and corresponding contacts on the wafer.

The system may include contacts on the interposer that are electrically-conductive and mechanically-compliant. The contacts may provide a mechanically-compliant electrical connection between the interposer and the corresponding contacts on the wafer. The contacts on the wafer may form an electrical circuit. The
5 additively-manufactured electrical conduits may include coaxial structures.

The circuit board further may include electronics associated with each of the electrical elements. Electronics associated with a corresponding electrical element may be for supporting operation of the corresponding electrical element.

The system may include pins between the interconnect and the wafer. where
10 the pins may be for providing at least part of an electrical pathway between the contacts and the interconnect. An interface board may be between the pins and the interconnect. The interface board may include at least part of the electrical pathway between the contacts and the interconnect. The interface board may include electronic components in the electrical pathway. The electronic components may be passive electronic components, such as capacitors, baluns and/or switches. The electronic components may include active electronic components.

Each of the electrical elements may be part of a radio frequency (RF) probe card. The electrical elements may include electrical cables that terminate on the circuit board. The contacts may be arranged in parallel rows on the wafer; and the
20 system may include a tester to make electrical contact between the interconnect and a subset of the contacts.

At least some of the additively-manufactured electrical conduits may be configured to have substantially matching electrical path lengths, impedances, and signal attenuation. The additively-manufactured electrical conduits may include curved or serpentine portions configured to achieve substantially matching electrical path lengths and time-of-flight, impedances, and signal attenuation between different additively-manufactured electrical conduits. The additively-manufactured electrical conduits may include three-dimensionally (3D) printed electrical conduits.

The second pitch may maintain a single dimension of the first pitch.

Also described herein is an example method that comprises: generating, via
10 an additive-manufacturing process, an interconnect comprising additively-manufactured electrical conduits that are part of an electrical pathway between electrical elements on a circuit board and contacts on a wafer, where the additively-manufactured electrical conduits comprise electrically-conductive material; and connecting the interconnect between the circuit board and the wafer. The circuit board comprises the electrical elements arranged at a first pitch; and the wafer comprises the contacts arranged at a second pitch, the second pitch being less than the first pitch. The example method may include one or more of the following features, either alone or in combination.

The additively-manufactured electrical conduits may comprise the electrically
20 conductive material surrounded by at least one dielectric material. The at least one dielectric material may be substantially surrounded by a layer of electrically-conductive material. The at least one dielectric material may comprise multiple

dielectric materials. The additively-manufactured electrical conduits may have a coaxial structure and the at least one dielectric may comprise air. The additively-manufactured electrical conduits may comprise electrically conductive material surrounded by a dielectric, where the dielectric is surrounded by a layer of electrically-conductive material. The at least one dielectric material may comprise at least one of air, ceramic and plastic

The method may further comprise connecting an interposer between the interconnect and the circuit board, where the interposer comprises a part of the electrical pathway between the electrical elements and the contacts. The method may further comprise connecting electrically-conductive pins between additively-manufactured electrical conduits in the interconnect and corresponding contacts on the wafer. The additively-manufactured electrical conduits may comprise coaxial structures. The circuit board may comprise electronics associated with each of the electrical elements, where electronics associated with a corresponding electrical element for supporting operation of the corresponding electrical element

The example method may further comprise providing spring pins between the interconnect and the wafer, where the spring pins for providing at least part of an electrical pathway between the contact., and the interconnect; and connecting an interface board between the pins and the interconnect, where the interface board is at least part of the electrical pathway between the contacts and the interconnect, and where the interface board comprises electronic components in the electrical pathway. The electronic components may be passive electronic components, such

as capacitors, baluns and/or switches. The electronic components may comprise active electronic components.

Each of the electrical elements may be part of a radio frequency (R F) probe card. The electrical elements may comprise electrical cables that terminate on the
5 circuit board. The contacts may be arranged in parallel rows on the wafer; and the method may further comprise causing a tester to make electrical contact between the interconnect and a subset of the contacts.

At least some of the additively-manufactured electrical conduits may be configured to have substantially matching electrical path lengths, impedances, and
10 signal attenuation. The additively-manufactured electrical conduits may comprise curved or serpentine portions configured to achieve substantially matching electrical path lengths, impedances, and signal attenuation between different additively-manufactured electrical conduits. The additive-manufacturing process may comprise a three-dimensional (3D) printing process. The additive-manufacturing process may comprise a printing process in which a three-dimensional (3D) structure is created by stacking layers of material.

The second pitch may maintain a single dimension of the first pitch.

Also described herein is an example system that comprises: a circuit board comprising electrical elements arranged at a first pitch; a wafer comprising contacts
20 arranged at a second pitch, where the second pitch is less than the first pitch; and an interconnect comprising subtractively-manufactured electrical conduits that are part of an electrical pathway between the electrical elements and the contacts. The

subtractively-manufactured electrical conduits may comprise electrically-conductive material. The subtractively-manufactured electrical conduits may have a stripline configuration, a microstrip configuration, or a co-planar waveguide configuration. Any two or more of the features described in this specification, including in

5 this summary section, can be combined to form implementations not specifically described herein.

The test systems and techniques described herein, or portions thereof, can be implemented as/controlled by a computer program product that includes instructions that are stored on one or more non-transitory machine-readable storage
10 media, and that are executable on one or more processing devices to control (e.g., coordinate) the operations described herein. The test systems and techniques described herein, or portions thereof, can be implemented as an apparatus, method, or electronic system that can include one or more processing devices and memory to store executable instructions to implement various operations.

The details of one or more implementations are set forth in the accompanying drawings and the description below. Other features and advantages will be apparent from the description and drawings, and from the claims.

DESCRIPTION OF THE DRAWINGS

Fig. 1 shows an example of a test board containing electronic devices.

Fig. 2 shows an example comparison of the pitch of electronic devices on a test board to the pitch of DUTs on a wafer.

Fig. 3 is an example of a test system containing a test board and an interconnect, and a wafer containing DUTs to be tested.

Fig. 4 is an example of an additively-manufactured electrical conduit.

Fig. 5 is an example of an additively-manufactured interconnect.

Fig. 6 is another example of an additively-manufactured interconnect.

Fig. 7 is an example of an additive-manufacturing process.

Fig. 8 is an example of part an additive-manufacturing process that may be used to produce an additively-manufactured interconnect having a coaxial structure.

Fig. 9 is a flowchart of a process for producing a test system of the type of

10 Fig.

Fig. 10 is an alternative example implementation of an interconnect,

Fig. 11 is an alternative example implementation of an interconnect.

Fig. 12 is a close-up, cut away view of the example interconnect of Fig. 11

Fig. 13. comprised of Figs. 13A, 13B and 13C, show different manufacturing techniques for producing conductive conduits for the interconnect.

Fig. 14 shows an example implementation of a test head of a test system that may be used with the interconnects described herein.

Like reference numerals in different figures indicate like elements.

DETAILED DESCRIPTION

Manufacturers may test devices at various stages of manufacturing. In an example manufacturing process, integrated circuits are fabricated in large quantities

on a single silicon wafer. The wafer is cut into individual integrated circuits called dice. Each die is loaded into a frame, and bonding wires are attached to connect the die to leads that extend from the frame. The loaded frame is then encapsulated in plastic or another packaging material to produce a finished product.

Manufacturers have an economic incentive to detect and discard faulty components as early as possible in the manufacturing process. Accordingly, many manufacturers test integrated circuits at the wafer level, before a wafer is cut. Defective circuits are identified and generally discarded prior to packaging, thus saving the cost of packaging defective dice. As a final check, many manufacturers

10 test each finished product before it is shipped. Such a process tests parts in packages that have had additional expense added to them over bare dice. So, having accurate test results reduces the need to discard valuable parts.

To test quantities of devices, manufacturers commonly use ATE, e.g. Automatic Test Equipment (or "testers"). In response to instructions in a test program set (TPS). ATE automatically generates input signals to be applied to a device under test (DUT), such as a bare die or dice, and monitors resulting output signals. The ATE compares the output signals with expected responses to determine whether each DUT is defective. ATE typically includes a computer system and a test instruments or devices having corresponding functionalities.

20 In some implementations. ATE is used to test electronic devices, or dice, at the wafer level. The electronic devices being tested on the wafer are the DUTs, and are different from electronic devices on a printed circuit board (PCB) that are

components that enable testing. In some implementations the PCB is used for radio frequency testing, and in other implementations the PCB may be used for other types of testing. In example implementations involving RF testing, components on the PCB for RF test are there, among other things, to provide a switching matrix

5 between the many RF channels coming from the DUT and the lesser number of test channels available in the tester. In example implementations that involve RF testing, also found on the PCB in the application space are baluns (used for impedance matching between the 50 ohm lines of the test system and the impedance(s) of the DUT) and capacitors which support the multiple power supplies of the DUTs by

10 providing shorter, lower-inductance connections between the stored energy in the capacitors and the DUT. This latter may be important in some instances because the DUT can switch power states so quickly that the power supply cannot track the desired voltage at the DUT due to the inductance of the lines connecting the power supply to the DUT. This phenomenon is a function of cable length and construction, and is compensated for by supplemental bypass capacitors mounted as electrically close as possible to the DUT. These bypass capacitors provide a nearby (connected by a relatively low-inductance path) reserve supply of stored energy which can be called upon by the DUT when it turns on and limits over-voltage spiking when the DUT turns off. Without the bypass capacitors both undervoltage

20 (sag) and overvoltage (spike) conditions can occur at the DUT, creating either soft or, potentially, hard failures.

The PCB may be used in testing DUTs (e.g., dice) on the wafer en masse, e.g., in parallel (or simultaneously). In an example implementation, the PCB may be part of (or form) a test probe card (e.g., an RF test or other test probe card), which itself may be part of a device interface board (DIB) of an ATE. The probe card may be used in performing tests on the DUTs on the wafer. For example, the probe card may be brought into contact with multiple DUTs on the wafer, and tests may be performed in parallel on those DUTs. In an example, the probe card may be brought into contact with a 2x8 block of adjacent DUTs on the wafer or with any other appropriate block of DUTs. Thereafter, the probe card may be moved to a different (e.g., adjacent) block of DUTs on the wafer, and those DUTS may be tested. This process may be repeated until all DUTs on the wafer are tested. Contact between the probe card and DUTs on the wafer is described below.

Fig. 14 shows an example test system 1400 that includes a PCB 1401, which constitutes a probe card, and which includes components such as those described herein. As shown, signals are routed between PCB 1401 and test electronics 1402, which may be part of a tester test head 1403. The test electronics may perform the actual testing on a DUT, e.g., by sending signals to the DUT, through cables 1404, PCB 1401, and interconnect 1405 (examples of which are described below).

Responses to those signals may retrace that path to reach the test electronics, where those responses are measured to determine whether a DUT is operating properly. In some implementations, the test electronics may have a different

configuration than that shown, and may perform processing outside of the test head, e.g., at one or more processing devices, such as a computer.

Examples of electronic devices 100 and associated circuitry 101 arranged at various sites on a PCB are shown in Fig. 1. Electronic devices on the PCB may be arranged at a specific pitch. In this implementation, a pitch includes the distance between parts (e.g., centers) of adjacent electronic devices. In other implementations, pitch may be defined differently. The pitch on the PCB is typically, although not necessarily, greater than the pitch of corresponding DUT contacts on the wafer. For instance, in some example implementations, the pitch on the PCB is 15mm and the pitch on the wafer is 5mm. Notably, the systems described herein may be used with any pitch values, and there may be cases where the pitches on the PCB and the wafer are the same.

Fig. 2 shows an example comparing the pitch of electronic devices 200 on a PCB to corresponding contacts 201 for DUTs on the wafer. As shown in Fig. 2, the DUT pattern for electronic devices 200 on the probe card has a difference in pitch than the actual DUTs 201 on the wafer.

The test systems described herein provide an interconnect to route signals between test circuitry electronic devices on the PCB and DUT contacts on the wafer. This is done using an interconnect that translates the pitch of the PCB to the pitch of the wafer. To this end, in an example implementation the electronic devices and associated circuitry are arranged on a PCB at a first pitch, e.g., with possibly inches between devices. The interconnect is used to translate from the first pitch space on

the PCB to a pitch on a wafer (a second pitch) that is smaller than the first pitch. In some implementations, an air-dielectric coaxial line is used in the interconnect. Using air as a dielectric may reduce dielectric losses while the lower dielectric constant of air may permit larger conductors and lower conductive losses for a given

5 impedance relative to most commonly used dielectrics; however, dielectrics other than air may be used. Using a coaxial configuration also may reduce skin depth conductivity losses. Heretofore, use of an air-dielectric coaxial line for wafer-level testing has been impractical due to the size of the wafer-level pitch.

10 In some implementations, the test systems described herein make use of an additive-manufacturing process to produce a coaxial line for wafer-level testing. In an example, an additive-manufacturing process, an example of which is 3D printing, may be used to produce coaxial lines at a pitch that can interface between electronic devices on the test PCB and wafer-level DUT contacts. Using additively-manufactured electrical conduits that are part of an electrical pathway between electronic devices on a PCB and DUT contacts on a wafer may improve parallel testing of some electronic devices.

In this regard, in order to promote consistency in signal transmission, electrical characteristics of different conduits should substantially match. For example, the impedances of different conduits should be controlled to be

20 substantially the same. In this context, impedance-controlled includes the ability to specify the impedance of individual conduits and to match the impedances of different conduits. Also, the electrical path length (as opposed to the physical path

length) as measured by ToF (Time of Flight) of the different conduits should be substantially the same. And, the signal attenuation produced by different electrical conduits should be substantially the same. In some implementations, all electrical conduits in the interconnect have the same impedance, electrical path length, and attenuation. In other implementations, this need not be the case. For example, in some implementations, the test electronics may account for, and/or correct for, variations in one or more of these parameters.

To this end, an example test system may include a circuit board (e.g., PCB) comprising electrical elements (e.g., electronic devices, cable terminations, etc.) arranged at a first pitch; a wafer comprising contacts arranged at a second pitch, where the second pitch is different from (e.g., less than or more than) the first pitch; and an interconnect comprising additively-manufactured electrical conduits that are part of an electrical pathway between the electrical elements and the contacts. In this example, the additively-manufactured electrical conduits comprise electrically-conductive material adjacent to a dielectric, such as air; however, in other examples, different types of electrical conduits may be used.

In an example implementation, the electrical elements used for testing include electronic devices that are part of a radio frequency (RF) probe function. In other implementations, the test systems described herein may be used to provide interconnects for different types of touch-down, or other, test functions.

Fig. 3 shows an example of a test system 300 of the type described above. Example test system 300 includes a PCB 301 of the type shown in Fig. 1, which

includes electrical elements. In this example, the electrical elements include electronic devices 302 that are part of a probe card used to perform wafer-level tests on a DUT.

However, the systems described herein are not limited to use with PCBs containing electronic devices that are part of a probe card. Rather, the electrical

5 elements may include, e.g., anything to or from which a signal can be routed. For example, the electrical elements may include cables or other types of electrical conduits that terminate on the PCB. In this example, the PCB also includes structural stiffener 304, such as that shown in Fig. 1. Also in this example, circuitry 325 is associated with each corresponding electronic device.

10 Electronic devices 302 are arranged at a first pitch, as shown in Fig. 3. The first pitch may be any distance between electronic devices. In the example of Fig. the pitch at which electronic devices 302 are arranged is greater than the pitch of corresponding DUT contacts on wafer 305. However, as noted above, in other implementations, this may not be the case. For example, in other implementations, the pitch at which electronic devices 302 are arranged may be less than, or equal to, the pitch of corresponding OUT contacts on wafer 305. Electronic devices 302 on PCB 301 map to corresponding DUT contacts 306 on wafer 305. That is, there is an electrical pathway between appropriate signal contacts on electronic devices 302 and corresponding DUT contacts on wafer 305. Accordingly, testing of a DUT on
20 wafer 305 may be enabled by electronic devices 302 on PCB 301 by routing signals to/from, DUTs on wafer 305 via the electrical pathway.

The electrical pathway between electronic devices 302 and contacts 306 on wafer 305 includes interconnect 309. In some implementations, interconnect 309 includes additively-manufactured electrical conduits that are impedance-controlled (e.g., manufactured or otherwise configured to attain a specified impedance or impedance range), that have a coaxial structure, and that simulate coaxial cables in terms of electrical performance. In some implementations, the additively-manufactured electrical conduits include electrically conductive material (e.g., metal, such as copper) immediately adjacent to (e.g., surrounded by or substantially surrounded by) a dielectric, such as air (e.g., an "air dielectric"). For example, from inner to outer, the sequence may proceed as: inner conductive material, air, outer material, and so forth, if applicable.

In some implementations, other dielectrics may be used in addition to, or instead of, air. Examples of such dielectrics include, but are not limited to, plastic, ceramic, and glass. In examples where air is used, additional dielectric material may be used to maintain and/or support spacing between an outer, non-air material and an interior conductive material adjacent to air. In some implementations, there may be additional dielectric material between the interior conductive material and the air. For example, from inner to outer, the sequence may proceed as: inner conductive material, dielectric, air, outer material and so forth, if applicable. Each dielectric in any implementation may be composed of multiple dielectric materials.

Fig. 4 shows an example of an additively-manufactured electrical conduit 400, which was produced via an additive-manufacturing process such as that described

below. Conduit 400 includes an inner conductive material 401, such as copper, surrounded, at least in part, by air 402. Around the air, and forming the structure of additively-manufactured electrical conduit 400, is another material 404. The other material may be metal and may act as a return path for the inner conductive

5 material. In other implementations, the additively-manufactured electrical conduit may have a structure and/or components that are different than those shown in Fig. 4. In some implementations the additive-manufacturing process used to produce the interconnect, including the electrical conduits, is three-dimensional (3D) printing. In other implementations, the additive-manufacturing process includes forming layers

10 upon layers to produce the resulting 3D structure, examples of which include, but are not limited to, electroforming and damascene construction. Sometimes, techniques such as these are referred to as 2 ¹/₂-D printing. In some definitions, a printing process becomes 2-1/2D when multiple layers of the printed product are stacked and that create interconnections between the layers. In other definitions, a process that produces even a single printed layer constitutes a 2-1/2D printing process because that single layer necessarily has thickness.

Fig. 5 shows an example of an interconnect 500 comprised of additively-manufactured electrical conduits 501, such as that shown in Fig. 4, that are impedance-controlled and that are part of an electrical pathway between electronic

20 devices on the PCB and DUT contacts on a wafer. In this example, an additively-manufactured electrical conduit 501 comprises electrically-conductive material adjacent to an air dielectric 502 and surrounded by another material 503. As noted

above, however, in some implementations, a dielectric other than air, or in addition to air, may be used. Example interconnect 500 translates electrical connection at a first pitch 505 of the PCB to a tighter (e.g., smaller), second pitch 506 of the wafer. Here, the first pitch corresponds to the separation of, and thus the electrical

5 connections of, electronic devices on the PCB, and the second pitch correspond to the separation of DUT contacts on the wafer.

In the example of Fig. 5 the relative thickness of the inner conductive material remains about the same throughout the interconnect, as does the size of the air dielectric. The amount of additional material, however, varies between the point
10 closest to the PCB and the point closest to the wafer. The additive-manufacturing process enables creation of such tight pitches near to the wafer. Throughout the structure of the interconnect, in some implementations, the physical relationship between the outer walls of the conduit and the central conductor are designed and created to form a fixed tuned relationship between the two, which may be measured by impedance, as in, for example, a 500 transmission line.

Fig. 6 shows another example of an interconnect 600 of the type described herein, which comprises additively-manufactured electrical conduits that are impedance-controlled and that are part of an electrical pathway between electronic devices on the PCB and DUT contacts on a wafer. In the example of Fig. 6,
20 interconnect 600 translates a pitch between groups 601 of electronic devices, which are separated by space 602, into a tighter pitch 604, in which DUT contacts for corresponding groups on the wafer are separated by a smaller space 606.

In some implementations, like that shown in Fig. 3, the electrical pathway between electronic devices on the PCB and contacts on the wafer includes structures in addition to interconnect 309. For example, such structures may include an interposer material 310 that electrically and physically connects PCB 301 and interconnect 309. The structures may also include a contactor assembly 312. Contactor assembly 312 may electrically and physically connect interconnect 309 and contacts 306 on wafer 305. In some implementations, contactor assembly 312 may include one or more pins (e.g., spring-based POGO® pins) that electrically and physically connect electrical conduits in the interconnect to corresponding contacts on the wafer. In other implementations, contactor assembly 312 may include one or more MEMS (Micro Electro-Mechanical Systems) devices that make the appropriate electrical and physical connection between electrical conduits in the interconnect and corresponding contacts on the wafer. In some implementations, fewer or more structures than are shown in Fig. 3 may be included.

In some implementations, the electrical pathway between electronic devices on the PCB and contacts on the wafer includes an interconnect only. In such implementations, structures and/or functions of interposer material 310, contactor assembly 312, and any other appropriate intermediary structures may be constructed as part of the interconnect during the additive-manufacturing process that forms the interconnect. In some example implementations, these structures may be formed inside of, or incorporated into, the interconnect via processes other than additive-manufacturing.

Examples of additive manufacturing process that may be used in the systems described herein include, but are not limited to, the MICA FreeformTM process developed by Microfabrica, Inc. of Van Nuys, California and the PolystrataTM process developed by Nuvotronics, LLC of Durham, North Carolina.

- 5 Fig. 7 shows an example of an additive-manufacturing process 700 that includes operations that may be used in a process for creating an interconnect of the type described herein (which includes additively-manufactured electrical conduits that are impedance-controlled and that comprise electrically-conductive material adjacent to a dielectric, such as air). Example process 700 begins (710) with a
- 10 planar substrate 701. A patterned polymer 702 is added (711) to planar substrate 701. A metallic layer 703 is added (712) on top of patterned polymer 702, which fills-in the pattern of the patterned polymer. The surface is then planarized (713) to remove the excess metal. Operations 710 to 713 are repeated (714) any appropriate number of times to create a layer stack 704 comprised of polymer with embedded metal. Once the appropriate number of layers are in the stack, the polymer is removed (715) using a solvent, thereby leaving the exposed metal 706. This basic process comprised of operations 710 to 715, however, is typically augmented to support the center of a coaxial line (e.g., a conductive material surrounded by an air dielectric).
- 20 For example, Fig. 8 shows an example of a process 800 that includes operations similar to those of process 700, and which may be used to generate an electrical conduit comprised of a conductive material surrounded by a dielectric,

such as air. According to process 800, a strata is formed by addition of layers until it is completed. The strata may be formed according to operations 710 to 714 above, e.g., through lithography, electroplating, and planarization to produce a structure comprised of patterned polymer with embedded metal layer(s). At one more points
5 during construction of a strata, dielectric straps 807 may be embedded (804) in the metal layers to support the inner conductive material 808. Multiple strata 809 may be built by performing successive operations including lithography, electroplating, and planarization. Thereafter, the polymer (or whatever resist is used) may be dissolved (805) to leave the resulting electrical conduit 810.

10 In other implementations, additive-manufacturing processes other than those described herein may be used to create the interconnect. For example, true 3D printing may be used to create the interconnect

Referring to Fig. 9, an interconnect may be produced by generating (901), via an additive-manufacturing process such as that shown in Fig. 8, an interconnect comprising additively-manufactured electrical conduits comprising electrically-conductive material adjacent to an air dielectric. The interposer material may be connected (902) to the interconnect as shown and the contactor assembly may be connected (903) to the interconnect as shown. The resulting structure may be connected to the PCB, to form a probe tester to perform wafer-level DUT testing.

20 The operations of Fig. 9 may be performed in a different order than that shown.

Referring back to Fig. 3, as part of a testing process, the structure 320 comprised of PCB 301, interposer material 310, interconnect 309, and contactor

assembly 312 may be brought into contact (e.g., electrical connection) with contacts for a block of DUTs 321. These DUTs may be tested in parallel, e.g., simultaneously. Thereafter, the structure 320 may be brought into contact with another block 322 of DUTs on wafer 305, and those DUTs may be tested in parallel.

- 5 This process may be repeated until all DUTs on the wafer are tested. The testing process may be computer controlled. For example, movement across a wafer may be computer-controlled, the application and analysis of test signals may be computer-controlled, and so forth.

Fig. 10 shows another example implementation of an additively-manufactured electrical interconnect 1001, and associated structures, to route signals between test
10 circuitry electronic devices (not shown) on a PCB 1002 and DUT contacts on a wafer (not shown). In the example implementation of Fig. 10, the additively-manufactured electrical interconnect includes individual additively-manufactured electrical conduits 1003. The individual additively-manufactured electrical conduits 1003 may be of the type described herein, e.g., they may be miniature coaxial structures, with each conduit comprising an electrically-conductive core (center), surrounded by a dielectric material, such as air, ceramic, glass, plastic, or the like. The electrically-conductive core is, in turn, surrounded by an electrically-conductive outer material that functions as an electrical return for the core. The electrically-conductive outer
20 material may, in turn, be surrounded by an insulator or isolated from other conductors by air, or may be electrically connected to the other outer material.

In the example interconnect 1001, at least some of (e.g., all of) the additively-manufactured electrical conduits are configured to have substantially matching electrical characteristics, such as electrical path lengths / Time of Flight (ToF), impedances, and signal attenuation. By substantially matching these electrical

5 characteristics, it is possible to reduce the chances that there will be differences in signal transmission time between conduits, and thereby reduce timing errors resulting from transmission through the interconnect. In this context, a substantial match may include a match that is identical or to within one or more predefined tolerances. In some implementations, it may only be appropriate to substantially

10 match only one or two of electrical path length, impedance, and signal attenuation.

In this implementation, matching electrical characteristics are achieved, at least in part, by using curved or serpentine conduit portions. For example, as shown in Fig. 10, individual conduits include curved or serpentine portions 1004. These portions are configured so that the electrical path lengths, impedances, and signal attenuation is the same among different conduits. In the example implementation of Fig. 10, conduits 1003a routes signals to points further from their origin than conduits 1003b. Without the curved or serpentine portions 1004, this difference

could result in conduits 1003a having different electrical characteristics than conduits 1003b. As a result, signals passing through conduits 1003a signals passing through

20 different conduits would have different electrical characteristics (e.g., timing, attenuation, etc.) than signals passing through conduits 1003b. However, the addition of curved or serpentine portions 1004 effectively elongates the signal

transmission path of conduits 1003b, thereby causing electrical characteristics of different conduits, such as electrical path lengths, impedances, and signal attenuation, to match, and thereby decreasing the possibility of different effects on different signals transmitted through different conduits of the interconnect.

- 5 Serpentine or curved portions may be added to any appropriate part or parts of a conduit to achieve desired electrical characteristics.

10 In the example implementation of Fig. 10, the pitch of the contacts on the wafer is maintained in one dimension (e.g. X-dimension 1007), but not in the other dimension (e.g., Y-dimension 1008). In other words, the spacing between conduits is spread out in Y-dimension 1008 relative to the contacts on the wafer. In the X-direction 1007, the spacing between conduits is about the same as the spacing between contacts on the wafer. In this example, for a group of conduits 1009, there are twelve conduits in X-direction 1007 and twelve conduits in Y-direction 1008. This may, or may not, be the case for each group of conduits shown in Fig. 10. This type of spacing can be advantageous. For example, it may be possible to add additional groups of conduits at the front or the back of the interconnect to accommodate larger numbers of wafer contacts.

20 Interconnect 1001 may also include a structure 1010, such as a circuit board, containing pins (e.g., spring contact pins, such as POGO® pins), which provide electrical connection to corresponding contacts on a DUT (the wafer). Electrical pathways pass through structure 1010 to reach circuit board 1011 (e.g., an interposer board). Circuit board 1011 includes active and/or passive electronic

components that are used to compensate for inductance in the electrical transmission paths between the wafer and the circuit board 1002. In some implementations, the passive electronic components may be capacitors, baluns, or switches: however, other active and/or passive electronic components may be used.

The electrical pathways extend through circuit board 1011 to the additively-manufactured electrical conduits 1003. From there, the electrical pathways extend to electrical elements on circuit board 1002, as described above.

In the above example, three screws 1012 (see also Fig. 11) are used as a mechanism to adjust the angle of structure 1010 so that plane (at which the pins
10 contact the DUT) is substantially parallel to circuit board 1002. For example, one or more of screws 1012 may be tightened or loosened in order to adjust the plane. In other implementations, different mechanisms may be used to make mechanical adjustments to keep the pins and the circuit board parallel.

Fig. 11 shows an example of an alternative implementation that uses microstrip construction, stripline construction or a co-planar waveguide construction to produce electrical conduits 1015 for transmitting signals through the interconnect. Each of these constructions is produced using etching and, therefore, is subtractively-manufactured in the sense that material is removed from the device to produce appropriate electrical and mechanical connections.

20 In this regard, to create an impedance-controlled channel two things are required: a force (often called the "signal") line and a return (often called "ground") line. A complete circuit is required to create a channel. The combination of the

force and return (signal and ground) describes the complete circuit. The geometric relationship between the force and return creates the impedance.

Referring to Fig. 13A in a stripline configuration, the impedance controlled signal line 1301 (the line that carries the signal forward, towards the DUT) is layered between two return (ground) planes 1302 (these are actually the "returns", in that the signal must have both a force and a return to create a complete circuit). The geometric relationship between those force and return lines is a factor in determining the impedance of the circuit. Resin and fabric 1303 may be between the conductive paths.

Referring to Fig. 13B, a microstrip configuration removes one of the ground planes, leaving the signal line 1304 and ground plane 1305. An advantage of a microstrip is that, if a true air environment can be enforced around the signal line, the electromagnetic losses as the signal passes down the trace will be less.

Referring to Fig. 13C, a coplanar waveguide is a form of microstrip where the ground plane 1307 is coplanar with the signal line 1308. The impedance is largely derived from the relationship of the traces on the surface of the structure. Coplanar waveguides are a good choice when signals are adjacent to each other that might be subject to crosstalk or inductive coupling between the traces.

Referring back to Fig. 11, each conduit in the interconnect may have a stripline configuration, a microstrip configuration or a coplanar waveguide configuration. Otherwise, the functions and features of the conduits are substantially the same as the additively-manufactured conduits described above. In Fig. 11,

different groups of conduits 1013 are covered with insulating material. A portion 1014 of the insulating material is removed to reveal the serpentine portions 1004 of conduits creating the electrical pathway between the wafer and the probe card. This is shown in close-up in Fig. 12.

Testing, as described herein, may be performed using a combination of system processing devices, embedded processing devices, and/or programmable logic. For example, each of these different elements may run on or more test programs to test multiple devices in parallel or in sequence.

10 While this specification describes example implementations related to "testing" and a "test system," the devices and method described herein may be used in any appropriate system, and are not limited to test systems or to the example test systems described herein.

Testing performed as described herein may be implemented and/or controlled using hardware or a combination of hardware and software. For example, a test system like the ones described herein may include various controllers and/or processing devices located at various points. A central computer may coordinate operation among the various controllers or processing devices. The central computer, controllers, and processing devices may execute various software routines to effect control and coordination of testing and calibration.

20 Testing can be controlled, at least in part, using one or more computer program products, e.g., one or more computer program tangibly embodied in one or more information carriers, such as one or more non-transitory machine-readable

media, for execution by, or to control the operation of, one or more data processing apparatus, e.g a programmable processor, a computer, multiple computers, and/or programmable logic components.

A computer program can be written in any form of programming language, including compiled or interpreted languages, and it can be deployed in any form, including as a stand-alone program or as a module, component, subroutine, or other unit suitable for use in a computing environment. A computer program can be deployed to be executed on one computer or on multiple computers at one site or distributed across multiple sites and interconnected by a network.

Actions associated with implementing all or part of the testing and calibration can be performed by one or more programmable processors executing one or more computer programs to perform the functions described herein. All or part of the testing and calibration can be implemented using special purpose logic circuitry, e.g. an FPGA (field programmable gate array) and/or an ASIC (application-specific integrated circuit).

Processors suitable for the execution of a computer program include, by way of example, both general and special purpose microprocessors, and any one or more processors of any kind of digital computer. Generally, a processor will receive instructions and data from a read-only storage area or a random access storage area or both. Elements of a computer (including a server) include one or more processors for executing instructions and one or more storage area devices for storing instructions and data. Generally, a computer will also include, or be

operatively coupled to receive data from, or transfer data to, or both, one or more machine-readable storage media, such as mass PCBs for storing data, e.g., magnetic, magneto-optical disks, or optical disks. Machine-readable storage media suitable for embodying computer program instructions and data include all forms of non-volatile storage area, including by way of example, semiconductor storage area devices, e.g EPROM, EEPROM, and flash storage area devices; magnetic disks, e.g., internal hard disks or removable disks; magneto-optical disks; and CD-ROM and DVD-ROM disks.

10 Any "electrical connection" as used herein may imply a direct physical connection or a connection that includes intervening components but that nevertheless allows electrical signals to flow between connected components. Any "connection" involving electrical circuitry mentioned herein, unless stated otherwise, is an electrical connection and not necessarily a direct physical connection regardless of whether the word "electrical" is used to modify "connection".

Elements of different implementations described herein may be combined to form other embodiments not specifically set forth above. Elements may be left out of the structures described herein without adversely affecting their operation. Furthermore, various separate elements may be combined into one or more individual elements to perform the functions described herein.

20 What is claimed is:

What is claimed is:

1. A system comprising:
 - a circuit board comprising electrical elements arranged at a first pitch;
 - a wafer comprising contacts arranged at a second pitch, the second pitch being less than the first pitch; and
 - an interconnect comprising electrical conduits comprised of layers of material, the electrical conduits being part of an electrical pathway between the electrical elements and the contacts, the electrical conduits comprising electrically-conductive material;wherein the electrical conduits have matching electrical impedances, the electrical conduits comprising coaxial structures, the coaxial structures having different physical configurations that produce the matching electrical impedances.
2. The system of claim 1, wherein the coaxial structures comprise at least one dielectric material.
3. The system of claim 2, wherein the at least one dielectric comprises air.
4. The system of claim 2, wherein the at least one dielectric material comprises air, plastic and/or ceramic.
5. The system of claim 1, further comprising:
 - an interposer between the interconnect and the circuit board, the interposer comprising a part of the electrical pathway between the electrical elements and the contacts.

6. The system of claim 1, further comprising:
electrically-conductive pins between electrical conduits in the interconnect and corresponding contacts on the wafer.
7. The system of claim 5, further comprising:
contacts on the interposer that are electrically-conductive and mechanically-compliant, the contacts to provide a mechanically-compliant electrical connection between the interposer and the corresponding contacts on the wafer.
8. The system of claim 7, wherein the contacts on the wafer form an electrical circuit.
9. The system of claim 1, wherein the coaxial structures comprise multiple dielectrics.
10. The system of claim 1, wherein the circuit board further comprises:
electronics associated with each of the electrical elements, wherein electronics associated with a corresponding electrical element are for supporting operation of the corresponding electrical element.
11. The system of claim 1, further comprising:
pins between the interconnect and the wafer, the pins for providing at least part of an electrical pathway between the contacts and the interconnect; and
an interface board between the pins and the interconnect, the interface board being at least part of the electrical pathway between the contacts and the interconnect, the interface board comprising electronic components in the electrical pathway.

12. The system of claim 11, wherein the electronic components are passive electronic components.

13. The system of claim 12, wherein the electronic components comprise at least one of capacitors, baluns or switches.

14. The system of claim 11, wherein the electronic components comprise active electronic components.

15. The system of claim 1, wherein each of the electrical elements comprises part of a radio frequency (RF) probe card.

16. The system of claim 1, wherein the electrical elements comprise electrical cables that terminate on the circuit board.

17. The system of claim 1, wherein the contacts are arranged in parallel rows on the wafer; and

wherein the system further comprises:

a tester to make electrical contact between the interconnect and a subset of the contacts.

18. The system of claim 1, wherein the electrical conduits are configured to have matching electrical path lengths, impedances, and signal attenuation.

19. The system of claim 1, wherein at least some of the electrical conduits are configured to have substantially matching electrical path lengths, impedances, and signal attenuation.

20. The system of claim 1, wherein the electrical conduits comprise curved or serpentine portions that produce substantially matching electrical path lengths and time-of-flight, impedances, and signal attenuation between different electrical conduits.

21. The system of claim 1, wherein the electrical conduits comprised three-dimensionally (3D) printed electrical conduits.

22. The system of claim 1, wherein the second pitch maintains a single dimension of the first pitch.

23. A system comprising:
a circuit board comprising electrical elements arranged at a first pitch;
a wafer comprising contacts arranged at a second pitch, the second pitch being less than the first pitch; and

an interconnect comprising electrical conduits comprised of layers of material, at least one of the layers missing at least some material, the electrical conduits being part of an electrical pathway between the electrical elements and the contacts, the electrical conduits comprising electrically-conductive material;

wherein the electrical conduits have matching electrical impedances, the electrical conduits comprising coaxial structures, the coaxial structures having different physical configurations to achieve the matching electrical impedances.

24. The system of claim 23, wherein the electrical conduits have a stripline configuration, a microstrip configuration, or a co-planar waveguide configuration.